Antoine Kahn

List of Publications by Citations

266 papers	27,368 citations	94 h-index	161 g-index
275 ext. papers	29,139 ext. citations	8.9 avg, IF	7.19 L-index

#	Paper	IF	Citations
266	A universal method to produce low-work function electrodes for organic electronics. *Science*, **2012**, 336, 327-32	33.3	1642
265	Transition metal oxides for organic electronics: energetics, device physics and applications. *Advanced Materials*, **2012**, 24, 5408-27	24	881
264	Electronic structure and electrical properties of interfaces between metals and π-conjugated molecular films. *Journal of Polymer Science, Part B: Polymer Physics*, **2003**, 41, 2529-2548	2.6	733
263	Charge-separation energy in films of π-conjugated organic molecules. *Chemical Physics Letters*, **2000**, 327, 181-188	2.5	665
262	Surface modification of indium tin oxide by plasma treatment: An effective method to improve the efficiency, brightness, and reliability of organic light emitting devices. *Applied Physics Letters*, **1997**, 70, 1348-1350	3.4	616
261	Electron Energetics at Surfaces and Interfaces: Concepts and Experiments. *Advanced Materials*, **2003**, 15, 271-277	24	564
260	Interface energetics in organo-metal halide perovskite-based photovoltaic cells. *Energy and Environmental Science*, **2014**, 7, 1377	35.4	554
259	Role of the deep-lying electronic states of MoO3 in the enhancement of hole-injection in organic thin films. *Applied Physics Letters*, **2009**, 95, 123301	3.4	547
258	Energetics of metal–organic interfaces: New experiments and assessment of the field. *Materials Science and Engineering Reports*, **2009**, 64, 1-31	30.9	526
257	Conjugated organic molecules on metal versus polymer electrodes: Demonstration of a key energy level alignment mechanism. *Applied Physics Letters*, **2003**, 82, 70-72	3.4	456
256	Molecular level alignment at organic semiconductor-metal interfaces. *Applied Physics Letters*, **1998**, 73, 662-664	3.4	402
255	Fermi level, work function and vacuum level. *Materials Horizons*, **2016**, 3, 7-10	14.4	396
254	The vibrational reorganization energy in pentacene: molecular influences on charge transport. *Journal of the American Chemical Society*, **2002**, 124, 7918-9	16.4	376
253	P-type doping of organic wide band gap materials by transition metal oxides: A case-study on Molybdenum trioxide. *Organic Electronics*, **2009**, 10, 932-938	3.5	368
252	Hybrid Organic-Inorganic Perovskites (HOIPs): Opportunities and Challenges. *Advanced Materials*, **2015**, 27, 5102-12	24	325
251	Controlled p-doping of zinc phthalocyanine by coevaporation with tetrafluorotetracyanoquinodimethane: A direct and inverse photoemission study. *Applied Physics Letters*, **2001**, 79, 4040-4042	3.4	307
250	MoO3 films spin-coated from a nanoparticle suspension for efficient hole-injection in organic electronics. *Advanced Materials*, **2011**, 23, 70-3	24	297

249	Lithium doping of semiconducting organic charge transport materials. *Journal of Applied Physics*, **2001**, 89, 4986-4992	2.5	295
248	Energetics of molecular interfaces. *Materials Today*, **2005**, 8, 32-41	21.8	290
247	Halide Perovskites: Is It All about the Interfaces?. *Chemical Reviews*, **2019**, 119, 3349-3417	68.1	287
246	Chemistry and electronic properties of metal-organic semiconductor interfaces: Al, Ti, In, Sn, Ag, and Au on PTCDA. *Physical Review B*, **1996**, 54, 13748-13758	3.3	286
245	Evidence for near-Surface NiOOH Species in Solution-Processed NiOx Selective Interlayer Materials: Impact on Energetics and the Performance of Polymer Bulk Heterojunction Photovoltaics. *Chemistry of Materials*, **2011**, 23, 4988-5000	9.6	283
244	Enhanced Efficiency in Plastic Solar Cells via Energy Matched Solution Processed NiOx Interlayers. *Advanced Energy Materials*, **2011**, 1, 813-820	21.8	273
243	Valence and Conduction Band Densities of States of Metal Halide Perovskites: A Combined Experimental-Theoretical Study. *Journal of Physical Chemistry Letters*, **2016**, 7, 2722-9	6.4	264
242	Organic semiconductor interfaces: electronic structure and transport properties. *Applied Surface Science*, **2000**, 166, 354-362	6.7	255
241	Surface oxidation activates indium tin oxide for hole injection. *Journal of Applied Physics*, **2000**, 87, 572-576	2.5	254
240	Controlled p doping of the hole-transport molecular material N,N?-diphenyl-N,N?-bis(1-naphthyl)-1,1?-biphenyl-4,4?-diamine with tetrafluorotetracyanoquinodimethane. *Journal of Applied Physics*, **2003**, 94, 359-366	2.5	244
239	Semiconductor surface structures. *Surface Science Reports*, **1983**, 3, 193-300	12.9	243
238	Energy level alignment at organic heterojunctions: Role of the charge neutrality level. *Physical Review B*, **2005**, 71,	3.3	242
237	Electronic structure and current injection in zinc phthalocyanine doped with tetrafluorotetracyanoquinodimethane: Interface versus bulk effects. *Organic Electronics*, **2002**, 3, 53-63	3.5	237
236	Electronic polarization at surfaces and thin films of organic molecular crystals: PTCDA. *Chemical Physics Letters*, **2002**, 360, 47-52	2.5	237
235	Polarization at the gold/pentacene interface. *Organic Electronics*, **2005**, 6, 85-91	3.5	229
234	Dipole formation at metal/PTCDA interfaces: Role of the Charge Neutrality Level. *Europhysics Letters*, **2004**, 65, 802-808	1.6	210
233	Spectroscopic study on sputtered PEDOT□PSS: Role of surface PSS layer. *Organic Electronics*, **2006**, 7, 387-396	3.5	209
232	Direct determination of the electronic structure of the poly(3-hexylthiophene):phenyl-[6,6]-C61 butyric acid methyl ester blend. *Organic Electronics*, **2010**, 11, 1779-1785	3.5	200

231	Molecules on si: electronics with chemistry. *Advanced Materials*, **2010**, 22, 140-59	24	197
230	Ultralow doping in organic semiconductors: evidence of trap filling. *Physical Review Letters*, **2012**, 109, 176601	7.4	192
229	Electronic structure of Vanadium pentoxide: An efficient hole injector for organic electronic materials. *Journal of Applied Physics*, **2011**, 110, 033710	2.5	190
228	Inverted Organic Solar Cells with Sol□Gel Processed High Work-Function Vanadium Oxide Hole-Extraction Layers. *Advanced Functional Materials*, **2011**, 21, 4776-4783	15.6	186
227	Impact of electrode contamination on the □NPD/Au hole injection barrier. *Organic Electronics*, **2005**, 6, 47-54	3.5	168
226	Dynamic scaling, island size distribution, and morphology in the aggregation regime of submonolayer pentacene films. *Physical Review Letters*, **2003**, 91, 136102	7.4	164
225	Effect of contamination on the electronic structure and hole-injection properties of MoO3/organic semiconductor interfaces. *Applied Physics Letters*, **2010**, 96, 133308	3.4	163
224	Energy level offset at organic semiconductor heterojunctions. *Journal of Applied Physics*, **1998**, 83, 2649-2655	2.5	162
223	Dynamical analysis of low-energy electron diffraction intensities from GaAs(110)-p(1□1)-Sb(1 ML). *Physical Review B*, **1982**, 26, 803-814	3.3	162
222	Mechanistic study on the solution-phase n-doping of 1,3-dimethyl-2-aryl-2,3-dihydro-1H-benzoimidazole derivatives. *Journal of the American Chemical Society*, **2013**, 135, 15018-25	16.4	159
221	Barrier formation at metal□organic interfaces: dipole formation and the charge neutrality level. *Applied Surface Science*, **2004**, 234, 107-112	6.7	159
220	Charge generation layers comprising transition metal-oxide/organic interfaces: Electronic structure and charge generation mechanism. *Applied Physics Letters*, **2010**, 96, 193302	3.4	157
219	Photoemission spectroscopy investigation of magnesium□Alq3 interfaces. *Journal of Applied Physics*, **1998**, 84, 355-358	2.5	156
218	Electron affinities of 1,1-diaryl-2,3,4,5-tetraphenylsiloles: direct measurements and comparison with experimental and theoretical estimates. *Journal of the American Chemical Society*, **2005**, 127, 9021-9	16.4	148
217	Hole-blocking titanium-oxide/silicon heterojunction and its application to photovoltaics. *Applied Physics Letters*, **2013**, 102, 203901	3.4	146
216	Impact of an interface dipole layer on molecular level alignment at an organic-conductor interface studied by ultraviolet photoemission spectroscopy. *Physical Review B*, **2004**, 70,	3.3	145
215	Correlation between EF pinning and development of metallic character in Ag overlayers on GaAs(110). *Physical Review Letters*, **1988**, 60, 440-443	7.4	145
214	Metal-dependent charge transfer and chemical interaction at interfaces between 3,4,9,10-perylenetetracarboxylic bisimidazole and gold, silver and magnesium. *Organic Electronics*, **2000**, 1, 5-13	3.5	144

213	Sensitization of silicon by singlet exciton fission in tetracene. *Nature*, **2019**, 571, 90-94	50.4	143
212	Pairing of near-ultraviolet solar cells with electrochromic windows for smart management of the solar spectrum. *Nature Energy*, **2017**, 2,	62.3	142
211	Organic semiconductor heterointerfaces containing bathocuproine. *Journal of Applied Physics*, **1999**, 86, 4515-4519	2.5	141
210	Electronic Level Alignment in Inverted Organometal Perovskite Solar Cells. *Advanced Materials Interfaces*, **2015**, 2, 1400532	4.6	139
209	Direct determination of the hole density of states in undoped and doped amorphous organic films with high lateral resolution. *Physical Review Letters*, **2005**, 95, 256405	7.4	139
208	n-Doping of organic electronic materials using air-stable organometallics. *Advanced Materials*, **2012**, 24, 699-703	24	138
207	The Role of Transition Metal Oxides in Charge-Generation Layers for Stacked Organic Light-Emitting Diodes. *Advanced Functional Materials*, **2010**, 20, 1762-1766	15.6	138
206	Energy level alignment at interfaces of organic semiconductor heterostructures. *Journal of Applied Physics*, **1998**, 84, 5583-5586	2.5	138
205	Low-temperature, solution-processed molybdenum oxide hole-collection layer for organic photovoltaics. *Journal of Materials Chemistry*, **2012**, 22, 3249		136
204	Combined photoemission/in vacuo transport study of the indium tin oxide/copper phthalocyanine/N,N?-diphenyl-N,N?-bis(l-naphthyl)-1,1?biphenyl-4,4?diamine molecular organic semiconductor system. *Journal of Applied Physics*, **1999**, 86, 2116-2122	2.5	136
203	Photovoltaic efficiency limits and material disorder. *Energy and Environmental Science*, **2012**, 5, 6022	35.4	134
202	Chemical and electrical properties of interfaces between magnesium and aluminum and tris-(8-hydroxy quinoline) aluminum. *Journal of Applied Physics*, **2001**, 89, 449-459	2.5	134
201	Dynamical calculation of low-energy electron diffraction intensities from GaAs(110): Influence of boundary conditions, exchange potential, lattice vibrations, and multilayer reconstructions. *Physical Review B*, **1979**, 19, 5194-5205	3.3	134
200	Induced Density of States model for weakly-interacting organic semiconductor interfaces. *Organic Electronics*, **2007**, 8, 241-248	3.5	128
199	Hydrogen passivation of germanium (100) surface using wet chemical preparation. *Applied Physics Letters*, **2005**, 87, 253101	3.4	128
198	Energy level alignment in PCDTBT:PC70BM solar cells: Solution processed NiOx for improved hole collection and efficiency. *Organic Electronics*, **2012**, 13, 744-749	3.5	127
197	Chemistry, diffusion, and electronic properties of a metal/organic semiconductor contact: In/perylenetetracarboxylic dianhydride. *Applied Physics Letters*, **1996**, 68, 217-219	3.4	124
196	Electron-hole interaction energy in the organic molecular semiconductor PTCDA. *Chemical Physics Letters*, **1997**, 272, 43-47	2.5	123

195	High-resolution synchrotron-radiation core-level spectroscopy of decapped GaAs(100) surfaces. *Physical Review B*, **1991**, 43, 14301-14304	3.3	122
194	Mixed-Halide Perovskites with Stabilized Bandgaps. *Nano Letters*, **2017**, 17, 6863-6869	11.5	121
193	Beating the thermodynamic limit with photo-activation of n-doping in organic semiconductors. *Nature Materials*, **2017**, 16, 1209-1215	27	120
192	Molecular n-Type Doping of 1,4,5,8-Naphthalene Tetracarboxylic Dianhydride by Pyronin B Studied Using Direct and Inverse Photoelectron Spectroscopies. *Advanced Functional Materials*, **2006**, 16, 831-837	15.6	119
191	How do electronic carriers cross Si-bound alkyl monolayers?. *Physical Review Letters*, **2005**, 95, 266807	7.4	119
190	Occupied and unoccupied electronic levels in organic π-conjugated molecules: comparison between experiment and theory. *Chemical Physics Letters*, **2000**, 317, 444-450	2.5	119
189	What is the Barrier for Tunneling Through Alkyl Monolayers? Results from n- and p-Si–Alkyl/Hg Junctions. *Advanced Materials*, **2007**, 19, 445-450	24	118
188	High-Work-Function Molybdenum Oxide Hole Extraction Contacts in Hybrid Organic-Inorganic Perovskite Solar Cells. *ACS Applied Materials & Interfaces*, **2016**, 8, 31491-31499	9.5	116
187	Interplay between morphology, structure, and electronic properties at diindenoperylene-gold interfaces. *Physical Review B*, **2003**, 68,	3.3	112
186	GaN (0001)-(1×1) surfaces: Composition and electronic properties. *Journal of Applied Physics*, **1998**, 83, 4249-4252	2.5	112
185	The Influence of Film Morphology in High-Mobility Small-Molecule:Polymer Blend Organic Transistors. *Advanced Functional Materials*, **2010**, 20, 2330-2337	15.6	110
184	Photoelectron Spectroscopic Study of the Electronic Band Structure of Polyfluorene and Fluorene-Arylamine Copolymers at Interfaces. *Journal of Physical Chemistry C*, **2007**, 111, 1378-1384	3.8	110
183	Improving charge injection in organic thin-film transistors with thiol-based self-assembled monolayers. *Organic Electronics*, **2008**, 9, 419-424	3.5	107
182	Band alignment at organic-inorganic semiconductor interfaces: α-NPD and CuPc on InP(110). *Journal of Applied Physics*, **1999**, 85, 6589-6592	2.5	107
181	The Influence of Steps on the Orientation of Copper Phthalocyanine Monolayers on Au(111). *Langmuir*, **2000**, 16, 4358-4361	4	105
180	Electronic structure, diffusion, and p-doping at the Au/F16CuPc interface. *Journal of Applied Physics* , **2001**, 90, 4549-4554	2.5	103
179	Electronic structure of Si(111)-bound alkyl monolayers: Theory and experiment. *Physical Review B*, **2006**, 74,	3.3	102
178	Gap states in pentacene thin film induced by inert gas exposure. *Physical Review Letters*, **2013**, 110, 267602	7.4	101

177	Energy-level alignment at interfaces between metals and the organic semiconductor 4,4?-N,N?-dicarbazolyl-biphenyl. *Journal of Applied Physics*, **1998**, 84, 3236-3241	2.5	101
176	Photoinduced Hole Transfer Becomes Suppressed with Diminished Driving Force in Polymer-Fullerene Solar Cells While Electron Transfer Remains Active. *Advanced Functional Materials*, **2013**, 23, 1238-1249	15.6	100
175	Titanium dioxide/silicon hole-blocking selective contact to enable double-heterojunction crystalline silicon-based solar cell. *Applied Physics Letters*, **2015**, 106, 123906	3.4	98
174	Modification of gold source and drain electrodes by self-assembled monolayer in staggered n- and p-channel organic thin film transistors. *Organic Electronics*, **2010**, 11, 227-237	3.5	96
173	Electronic states and effective negative electron affinity at cesiated p-GaN surfaces. *Journal of Applied Physics*, **1999**, 86, 3209-3212	2.5	95
172	The origin of low water vapor transmission rates through Al2O3/ZrO2 nanolaminate gas-diffusion barriers grown by atomic layer deposition. *Applied Physics Letters*, **2010**, 96, 243308	3.4	94
171	Organic molecular films on gold versus conducting polymer: Influence of injection barrier height and morphology on current–voltage characteristics. *Applied Physics Letters*, **2003**, 82, 2281-2283	3.4	91
170	Revisiting the Valence and Conduction Band Size Dependence of PbS Quantum Dot Thin Films. *ACS Nano*, **2016**, 10, 3302-11	16.7	89
169	Phosphine Oxide Derivatives as Hosts for Blue Phosphors: A Joint Theoretical and Experimental Study of Their Electronic Structure. *Chemistry of Materials*, **2010**, 22, 247-254	9.6	89
168	Decamethylcobaltocene as an efficient n-dopant in organic electronic materials and devices. *Organic Electronics*, **2008**, 9, 575-581	3.5	89
167	Stability of inverted organic solar cells with ZnO contact layers deposited from precursor solutions. *Energy and Environmental Science*, **2015**, 8, 592-601	35.4	88
166	N-type doping of an electron-transport material by controlled gas-phase incorporation of cobaltocene. *Chemical Physics Letters*, **2006**, 431, 67-71	2.5	86
165	Air-Exposure-Induced Gas-Molecule Incorporation into Spiro-MeOTAD Films. *Journal of Physical Chemistry Letters*, **2014**, 5, 1374-9	6.4	81
164	Use of a high electron-affinity molybdenum dithiolene complex to p-dope hole-transport layers. *Journal of the American Chemical Society*, **2009**, 131, 12530-1	16.4	81
163	Correlation between interface energetics and open circuit voltage in organic photovoltaic cells. *Applied Physics Letters*, **2012**, 101, 233301	3.4	81
162	Interfacial charge-transfer doping of metal halide perovskites for high performance photovoltaics. *Energy and Environmental Science*, **2019**, 12, 3063-3073	35.4	77
161	Doping-induced realignment of molecular levels at organic–organic heterojunctions. *Chemical Physics*, **2006**, 325, 129-137	2.3	77
160	Solution doping of organic semiconductors using air-stable n-dopants. *Applied Physics Letters*, **2012**, 100, 083305	3.4	76

159	Effect of electrical doping on molecular level alignment at organic/organic heterojunctions. *Applied Physics Letters*, **2003**, 82, 4815-4817	3.4	76
158	The role of interface states in controlling the electronic structure of Alq3/reactive metal contacts. *Organic Electronics*, **2001**, 2, 89-95	3.5	75
157	Electronic structure of the CsPbBr3/polytriarylamine (PTAA) system. *Journal of Applied Physics*, **2017**, 121, 035304	2.5	74
156	Synthesis, ionisation potentials and electron affinities of hexaazatrinaphthylene derivatives. *Chemistry - A European Journal*, **2007**, 13, 3537-47	4.8	74
155	Transparent stacked organic light emitting devices. I. Design principles and transparent compound electrodes. *Journal of Applied Physics*, **1999**, 86, 4067-4075	2.5	73
154	Device Characteristics of Bulk-Heterojunction Polymer Solar Cells are Independent of Interfacial Segregation of Active Layers. *Chemistry of Materials*, **2011**, 23, 2020-2023	9.6	71
153	Enhanced Charge-Carrier Injection and Collection Via Lamination of Doped Polymer Layers p-Doped with a Solution-Processible Molybdenum Complex. *Advanced Functional Materials*, **2014**, 24, 2197-2204	15.6	70
152	Band lineup at an organic-inorganic semiconductor heterointerface: perylenetetracarboxylic dianhydride/GaAs(100). *Applied Physics Letters*, **1994**, 64, 3482-3484	3.4	69
151	ZnSe/GaAs and Se/GaAs interfaces. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **1985**, 3, 922-925	2.9	68
150	Energy level and band alignment for GaAs-alkylthiol monolayer-Hg junctions from electrical transport and photoemission experiments. *Journal of Physical Chemistry B*, **2006**, 110, 14363-71	3.4	66
149	Chemically Controlled Reversible and Irreversible Extraction Barriers Via Stable Interface Modification of Zinc Oxide Electron Collection Layer in Polycarbazole-based Organic Solar Cells. *Advanced Functional Materials*, **2014**, 24, 4671-4680	15.6	64
148	Electrical doping: the impact on interfaces of π-conjugated molecular films. *Journal of Physics Condensed Matter*, **2003**, 15, S2757-S2770	1.8	62
147	Electronic states at aluminum nitride (0001)-1×1 surfaces. *Applied Physics Letters*, **1999**, 74, 546-548	3.4	61
146	A Molybdenum Dithiolene Complex as p-Dopant for Hole-Transport Materials: A Multitechnique Experimental and Theoretical Investigation. *Chemistry of Materials*, **2010**, 22, 524-531	9.6	60
145	Organometallic Chemistry at the Magnesium/Tris(8-hydroxyquinolino)aluminum Interface. *Journal of the American Chemical Society*, **2000**, 122, 5391-5392	16.4	60
144	Low-Temperature Synthesis of a TiO2/Si Heterojunction. *Journal of the American Chemical Society*, **2015**, 137, 14842-5	16.4	59
143	NiOX/MoO3 Bi-Layers as Efficient Hole Extraction Contacts in Organic Solar Cells. *Advanced Functional Materials*, **2014**, 24, 701-706	15.6	59
142	What Limits the Open-Circuit Voltage of Bromide Perovskite-Based Solar Cells?. *ACS Energy Letters*, **2019**, 4, 1-7	20.1	58

141	Molecular-Level Offset at the PTCDA/Alq3 Heterojunction. *Advanced Materials*, **1998**, 10, 140-144	24	56
140	Physisorption-like Interaction at the Interfaces Formed by Pentacene and Samarium. *Journal of Physical Chemistry B*, **2002**, 106, 4192-4196	3.4	56
139	Charge transfer at n-doped organic-organic heterojunctions. *Journal of Applied Physics*, **2009**, 105, 123711	2.5	53
138	Passivation of trap states in unpurified and purified C60 and the influence on organic field-effect transistor performance. *Applied Physics Letters*, **2012**, 101, 253303	3.4	52
137	Hg/Molecular Monolayer/Si Junctions: Electrical Interplay between Monolayer Properties and Semiconductor Doping Density. *Journal of Physical Chemistry C*, **2010**, 114, 10270-10279	3.8	51
136	Elucidating the Role of a Tetrafluoroborate-Based Ionic Liquid at the n-Type Oxide/Perovskite Interface. *Advanced Energy Materials*, **2020**, 10, 1903231	21.8	50
135	Dopant controlled trap-filling and conductivity enhancement in an electron-transport polymer. *Applied Physics Letters*, **2015**, 106, 163301	3.4	49
134	Characterization of the Valence and Conduction Band Levels of n = 1 2D Perovskites: A Combined Experimental and Theoretical Investigation. *Advanced Energy Materials*, **2018**, 8, 1703468	21.8	48
133	Charge transport across metal/molecular (alkyl) monolayer-Si junctions is dominated by the LUMO level. *Physical Review B*, **2012**, 85,	3.3	48
132	Determination of Energy Level Alignment within an Energy Cascade Organic Solar Cell. *Chemistry of Materials*, **2016**, 28, 794-801	9.6	47
131	Tailoring Electron-Transfer Barriers for Zinc Oxide/C60 Fullerene Interfaces. *Advanced Functional Materials*, **2014**, 24, 7381-7389	15.6	47
130	Oriented Growth of Al2O3:ZnO Nanolaminates for Use as Electron-Selective Electrodes in Inverted Polymer Solar Cells. *Advanced Functional Materials*, **2012**, 22, 1531-1538	15.6	47
129	Role of metal/molecule chemistry and interdiffusion on the electrical properties of an organic interface: The Al/F16CuPc case. *Journal of Applied Physics*, **2001**, 90, 6236-6242	2.5	47
128	Halogenation of a Nonplanar Molecular Semiconductor to Tune Energy Levels and Bandgaps for Electron Transport. *Chemistry of Materials*, **2015**, 27, 1892-1900	9.6	46
127	Structure determination for the (110) surface of zincblende structure compound semiconductors. *Journal of Vacuum Science and Technology*, **1979**, 16, 1252-1257		46
126	N-doping of pentacene by decamethylcobaltocene. *Applied Physics A: Materials Science and Processing*, **2009**, 95, 7-13	2.6	45
125	Filled and empty states of alkanethiol monolayer on Au (111): Fermi level asymmetry and implications for electron transport. *Chemical Physics Letters*, **2011**, 511, 344-347	2.5	44
124	Investigation of the High Electron Affinity Molecular Dopant F6-TCNNQ for Hole-Transport Materials. *Advanced Functional Materials*, **2018**, 28, 1703780	15.6	44

123	Ordered, quasiepitaxial growth of an organic thin film on Se-passivated GaAs(100). *Applied Physics Letters*, **1995**, 66, 944-946	3.4	42
122	Synchrotron-radiation-induced surface photovoltage on GaAs studied by contact-potential-difference measurements. *Physical Review B*, **1990**, 42, 3228-3230	3.3	42
121	Electronic structure of the poly(3-hexylthiophene):indene-C60 bisadduct bulk heterojunction. *Journal of Applied Physics*, **2011**, 110, 043719	2.5	41
120	Electronic Current Transport through Molecular Monolayers: Comparison between Hg/Alkoxy and Alkyl Monolayer/Si(100) Junctions. *Advanced Materials*, **2008**, 20, 3931-3936	24	41
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118	The atomic geometries of GaP(110) and ZnS(110) revisited: A structural ambiguity and its resolution. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **1984**, 2, 515-518	2.9	39
117	Influence of chemical doping on the performance of organic photovoltaic cells. *Applied Physics Letters*, **2009**, 94, 203306	3.4	38
116	Silicon surface passivation by an organic overlayer of 9,10-phenanthrenequinone. *Applied Physics Letters*, **2010**, 96, 222109	3.4	37
115	Self-passivated copper gates for amorphous silicon thin-film transistors. *IEEE Electron Device Letters*, **1997**, 18, 388-390	4.4	37
114	Surface order and stoichiometry of sputter-cleaned and annealed CuInSe2. *Journal of Applied Physics*, **1985**, 57, 2967-2969	2.5	37
113	Investigation of p-dopant diffusion in polymer films and bulk heterojunctions: Stable spatially-confined doping for all-solution processed solar cells. *Organic Electronics*, **2015**, 23, 151-157	3.5	36
112	Electronic Structure and Dynamics at Organic Donor/Acceptor Interfaces. *MRS Bulletin*, **2010**, 35, 443-448	3.2	36
111	Enhancement of electron injection into a light-emitting polymer from an aluminum oxide cathode modified by a self-assembled monolayer. *Applied Physics Letters*, **2008**, 93, 103305	3.4	36
110	Remote doping of a pentacene transistor: Control of charge transfer by molecular-level engineering. *Applied Physics Letters*, **2010**, 97, 123305	3.4	33
109	Isolated molecular dopants in pentacene observed by scanning tunneling microscopy. *Physical Review B*, **2009**, 80,	3.3	33
108	Incorporation of cobaltocene as an n-dopant in organic molecular films. *Journal of Applied Physics*, **2007**, 102, 014906	2.5	33
107	Radiation damage to alkyl chain monolayers on semiconductor substrates investigated by electron spectroscopy. *Journal of Physical Chemistry B*, **2006**, 110, 21826-32	3.4	33
106	Quantifying the Extent of Contact Doping at the Interface between High Work Function Electrical Contacts and Poly(3-hexylthiophene) (P3HT). *Journal of Physical Chemistry Letters*, **2015**, 6, 1303-9	6.4	32

105	Hole Injection in a Model Fluorene□Triarylamine Copolymer. *Advanced Functional Materials*, **2009**, 19, 304-310	15.6	32
104	Chemistry between magnesium and multiple molecules in tris(8-hydroxyquinoline) aluminum films. *Journal of the American Chemical Society*, **2003**, 125, 7808-9	16.4	31
103	Direct and inverse photoemission spectroscopy studies of potassium intercalated films of two organic semiconductors. *Applied Physics Letters*, **2003**, 83, 500-502	3.4	31
102	Doping Molecular Monolayers: Effects on Electrical Transport Through Alkyl Chains on Silicon. *Advanced Functional Materials*, **2008**, 18, 2102-2113	15.6	29
101	Role of Electrode Contamination in Electron Injection at Mg:Ag/Alq3 Interfaces. *Advanced Materials* , **1999**, 11, 1523-1527	24	29
100	Contorted Hexabenzocoronenes with Extended Heterocyclic Moieties Improve Visible-Light Absorption and Performance in Organic Solar Cells. *Chemistry of Materials*, **2016**, 28, 673-681	9.6	28
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95	Negative electron affinity at the Cs/AlN(0001) surface. *Applied Physics Letters*, **1999**, 74, 1433-1435	3.4	28
94	Molecular doping and tuning threshold voltage in 6,13-bis(triisopropylsilylethynyl)pentacene/polymer blend transistors. *Applied Physics Letters*, **2014**, 105, 063301	3.4	27
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